

## EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	1056	204/416.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	ADJ	OFF	2009/01/12 11:37
L2	290	422/82.03.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	ADJ	OFF	2009/01/12 11:38
L3	449	438/142.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	ADJ	OFF	2009/01/12 11:38
L4	114	(I1 or I2 or I3) and (ion near5 transistor)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	ADJ	OFF	2009/01/12 11:38
L5	1	(I1 or I2 or I3) and (ion near5 transistor) and pass transistor	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	ADJ	OFF	2009/01/12 11:39
L6	24	(I1 or I2 or I3) and (ion near5 transistor) and ((input or voltage) near3 drain)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	ADJ	OFF	2009/01/12 11:41
L7	353	257/253.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	ADJ	OFF	2009/01/12 11:50
L8	86	I7 and ((pass transistor) or ((input or voltage) near3 drain))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	ADJ	OFF	2009/01/12 11:50
L9	83	I7 and ((pass transistor) or ((input or voltage) near3 drain)) and reference	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	ADJ	OFF	2009/01/12 11:57
L10	8149	pass transistor	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	ADJ	OFF	2009/01/12 12:04

L11	51	I10 and (ion near5 concentration)	US-PGRUB; USPAT; USOCR; EPO; JPO; DERWENT	ADJ	OFF	2009/01/12 12:04
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1/ 12/ 2009 12:09:57 PM